Quad exclusive OR gate BU4030B / BU4030BF BU4070B / BU4070BF

The BU4030B / F and BU4070B / F are exclusive OR gates.

Four circuits are contained on a single chip. An inverter-based buffer is added to the gate output for an enhanced I / O voltage characteristic, and the load capacitance has been increased to minimize fluctuation in the propagation time. In addition, these products feature low power consumption and a high noise margin.

These can also be used in digital comparators and parity circuit applications.

Features

- 1) Low power dissipation.
- 2) Wide range of operating power supply voltages.
- 3) High input impedance.

- 4) High fan-out.
- 5) Direct drive of 2 L-TTL inputs and 1 LS-TTL input.

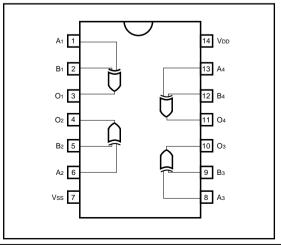
●Absolute maximum ratings (Vss = 0V, Ta = 25°C)

Parameter	Symbol	Symbol Limits	
Power supply voltage	V _{DD}	− 0.3 ~ + 18	V
Power dissipation	Pd	1000 (DIP), 450 (SOP)	mW
Operating temperature	Topr	− 40 ~ + 85	°C
Storage temperature	Tstg	− 55 ~ + 150	°C
Input voltage	Vin	- 0.3 ~ V _{DD} + 0.3	V

Truth table

INF	OUTPUT		
Α	В	001701	
L	L	L	
L	Н	Н	
Н	L	Н	
Н	Н	L	

Block diagram



Electrical characteristics

DC characteristics (unless otherwise noted, Vss = 0V, Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions		Measurement
						V _{DD} (V)	Conditions	circuit
Input high level voltage	Vih	3.5	_	_	V	5	_	Fig.1
		7.0	_	_		10		
		11.0	_	_		15		
		_	_	1.5		5	_	
Input low level voltage	VIL	_	_	3.0	V	10		Fig.1
		_	_	4.0		15		
Input high level current	lін	_	_	0.3	μΑ	15	Vін = 15V	Fig.1
Input low level current	lı∟	_	_	- 0.3	μΑ	15	VIL = 0V	Fig.1
	Vон	4.95	_	_		5	lo = 0mA	Fig.1
Output high level voltage		9.95	_	_	V	10		
		14.95	_	_		15		
Output low level voltage	Vol	_	_	0.05	V	5	lo = 0mA	Fig.1
		_	_	0.05		10		
		_	_	0.05		15		
Output high level current	Іон	- 0.16	_	_	mA	5	Vон = 4.6V	Fig.1
		- 0.4	_	_		10	Vон = 9.5V	
		- 1.2	_	_		15	Vон = 13.5V	
Output low level current	loL	0.44	_	_	mA	5	Vol = 0.4V	Fig.1
		1.1	_	_		10	Vol = 0.5V	
		3.0	_	_		15	Vol = 1.5V	
Static current dissipation	loo	_	_	1	μΑ	5	VI = VDD or GND	
		_	_	2		10		_
		_		4		15		

Switching characteristics (unless otherwise noted, Vss = 0V, Ta = 25°C, CL = 50 pF)

Parameter	Symbol	Min.	Тур.	Max.	Unit.	V _{DD} (V)	Conditions	Measurement circuit
Output rise time	tтьн	_	180	_	ns	5	_	Fig.2
		_	90	_		10		
		_	65	_		15		
Output fall time	tтн∟	_	100	_	ns	5	_	Fig.2
		_	50	_		10		
		_	40	_		15		
"L" to "H" propagation delay time	tрLн	_	175	_	ns	5	_	Fig.2
		_	75	_		10		
		_	50	_		15		
"H" to "L" propagation delay time	tрнL	_	175	_	ns	5	_	Fig.2
		_	75	_		10		
		_	50	_		15		
Input capacitance	Cı	_	5	_	pF	_	_	_

Measurement circuits

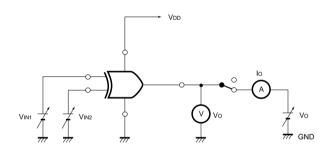


Fig. 1 DC characteristics measurement circuit

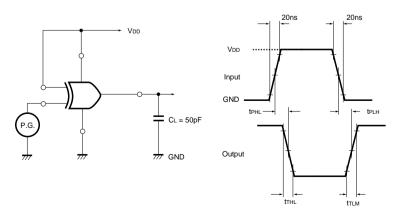


Fig. 2 Switching characteristics measurement circuit

Electrical characteristic curve

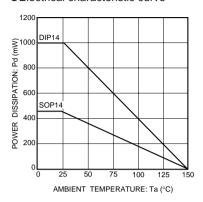
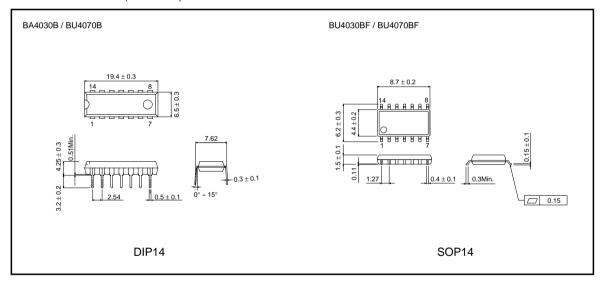


Fig.3 Power dissipation vs. Ta

External dimensions (Units: mm)



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